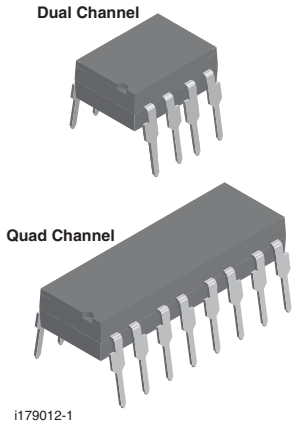
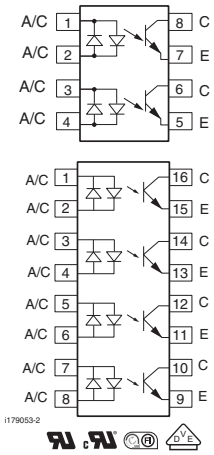
Optocoupler, Phototransistor Output, AC Input (Dual, Quad Channel)





FEATURES

- Identical channel to channel footprint
- ILD620 crosses to TLP620-2
- ILQ620 crosses to TLP620-4
- High collector emitter voltage, BV_{CEO} = 70 V
- Dual and quad packages feature:
  - Reduced board space
  - Lower pin and parts count
  - Better channel to channel CTR match
  - Improved common mode rejection
- Isolation test voltage 5300 V_{RMS}
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Pb-free

e3

RoHS COMPLIANT

DESCRIPTION

The ILD620, ILQ620, ILD620GB, and ILQ620GB are multi-channel input phototransistor optocouplers that use inverse parallel GaAs IRLED emitter and high gain NPN silicon phototransistors per channel. These devices are constructed using over/under leadframe optical coupling and double molded insulation resulting in a withstand test voltage of 5300 V_{RMS}.

The LED parameters and the linear CTR characteristics make these devices well suited for AC voltage detection. The ILD620GB and ILQ620GB with its low I_F guaranteed CTR_{CEsat} minimizes power dissipation of the A_C voltage detection network that is placed in series with the LEDs. Eliminating the phototransistor base connection provides added electrical noise immunity from the transients found in many industrial control environments.

AGENCY APPROVALS

- UL1577, file no. E52744 system code H, double protection
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 pending available with option 1
- FIMKO

ORDERING INFORMATION

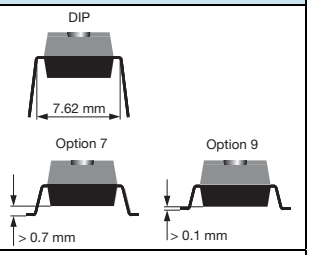
I	L	x	6	2	0	x	x	-	X	0	#	#	T

PART NUMBER

x = D (Dual) or Q (Quad)

PACKAGE OPTION

TAPE AND REEL



AGENCY CERTIFIED/PACKAGE	DUAL CHANNEL		QUAD CHANNEL	
	CTR (%)			
UL, cUL, FIMKO	**50 to 600**	**100 to 600**	**50 to 600**	**100 to 600**
DIP-8	ILD620	ILD620GB	-	-
SMD-8, option 7	ILD620-X007T (1)	-	-	-
SMD-8, option 9	ILD620-X009T (1)	ILD620GB-X009T (1)	-	-
DIP-16	-	-	ILQ620	ILQ620GB
SMD-16, option 7	-	-	ILQ620-X007	-
SMD-16, option 9	-	-	ILQ620-X009T (1)	ILQ620GB-X009T (1)
VDE, UL, cUL, FIMKO	**50 to 600**	**100 to 600**	**50 to 600**	**100 to 600**
DIP-16	-	-	ILQ620-X001	-
SMD-16, option 9	-	-	ILQ620-X019T (1)	-

Notes

- Additional options may be possible, please contact sales office.

(1) Also available in tubes, do not put T on the end.

For technical questions, contact: optocoupleranswers@vishay.com

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)					
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**VALUE**	**UNIT**
INPUT					
Forward current			I_F	± 60	mA
Surge current			I_{FSM}	± 1.5	A
Power dissipation			P_{diss}	100	mW
Derate linearly from 25 °C				1.3	mW/°C
OUTPUT					
Collector emitter breakdown voltage			BV_{CEO}	70	V
Collector current			I_C	50	mA
	t < 1 s		I_C	100	mA
Power dissipation			P_{diss}	150	mW
Derate from 25 °C				2	mW/°C
COUPLER					
Isolation test voltage	t = 1 s		V_{ISO}	5300	V_{RMS}
Isolation voltage			V_{IORM}	890	V_P
Total power dissipation			P_{tot}	250	mW
Package dissipation		ILD620		400	mW
		ILD620GB		400	mW
Derate from 25 °C				5.33	mW/°C
Package dissipation		ILQ620		500	mW
		ILQ620GB		500	mW
Derate from 25 °C				6.67	mW/°C
Creepage distance				≥ 7	mm
Clearance distance				≥ 7	mm
Isolation resistance	V_{IO} = 500 V, T_{amb} = 25 °C		R_{IO}	≥ 10^{12}	Ω
	V_{IO} = 500 V, T_{amb} = 100 °C		R_{IO}	≥ 10^{11}	Ω
Storage temperature			T_{stg}	- 55 to + 150	°C
Operating temperature			T_{amb}	- 55 to + 100	°C
Junction temperature			T_j	100	°C
Soldering temperature (1)	2 mm from case bottom		T_{sld}	260	°C

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

(1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
INPUT							
Forward voltage	I_F = ± 10 mA		V_F	1	1.15	1.3	V
Forward current	V_R = ± 0.7 V		I_F		2.5	20	µA
Capacitance	V_F = 0 V, f = 1 MHz		C_O		25		pF
Thermal resistance, junction to lead			R_{thJL}		750		K/W
OUTPUT							
Collector emitter capacitance	V_{CE} = 5 V, f = 1 MHz		C_{CE}		6.8		pF
Collector emitter leakage current	V_{CE} = 24 V		I_{CEO}		10	100	nA
	T_A = 85 °C, V_{CE} = 24 V		I_{CEO}		2	50	µA
Thermal resistance, junction to lead			R_{thJL}		500		K/W

For technical questions, contact: optocoupleranswers@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
COUPLER							
Off-state collector current	V_F = ± 0.7 V, V_{CE} = 24 V		I_{CEoff}		1	10	µA
Collector emitter saturation voltage	I_F = ± 8 mA, I_{CE} = 2.4 mA	ILD620	V_{CEsat}			0.4	V
		ILQ620	V_{CEsat}			0.4	V
	I_F = ± 1 mA, I_{CE} = 0.2 mA	ILD620GB	V_{CEsat}			0.4	V
		ILQ620GB	V_{CEsat}			0.4	V

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T_{amb} = 25 °C, unless otherwise specified)							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Channel/channel CTR match	I_F = ± 5 mA, V_{CE} = 5 V		CTRX/CTRY	1 to 1		3 to 1	
CTR symmetry	I_{CE} (I_F = - 5 mA)/I_{CE} (I_F = + 5 mA)		$I_{CE(RATIO)}$	0.5		2	
Current transfer ratio (collector emitter saturated)	I_F = ± 1 mA, V_{CE} = 0.4 V	ILD620	CTR_{CEsat}		60		%
		ILQ620	CTR_{CEsat}		60		%
Current transfer ratio (collector emitter)	I_F = ± 5 mA, V_{CE} = 5 V	ILD620	CTR_{CE}	50	80	600	%
		ILQ620	CTR_{CE}	50	80	600	%
Current transfer ratio (collector emitter saturated)	I_F = ± 1 mA, V_{CE} = 0.4 V	ILD620GB	CTR_{CEsat}	30			%
		ILQ620GB	CTR_{CEsat}	30			%
Current transfer ratio (collector emitter)	I_F = ± 5 mA, V_{CE} = 5 V	ILD620GB	CTR_{CEsat}	100	200	600	%
		ILQ620GB	CTR_{CEsat}	100	200	600	%

SAFETY AND INSULATION RATED PARAMETERS						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Partial discharge test voltage - routine test	100 %, t_{test} = 1 s	V_{pd}	1.669			kV
Partial discharge test voltage - lot test (sample test)	t_{Tr} = 60 s, t_{test} = 10 s, (see figure 2)	V_{IOTM}	10			kV
		V_{pd}	1.424			kV
Insulation resistance	V_{IO} = 500 V	R_{IO}	10^{12}			Ω
	V_{IO} = 500 V, T_{amb} = 100 °C	R_{IO}	10^{11}			Ω
	V_{IO} = 500 V, T_{amb} = 150 °C (construction test only)	R_{IO}	10^{9}			Ω
Forward current		I_{si}			275	mA
Power dissipation		P_{SO}			400	mW
Rated impulse voltage		V_{IOTM}			10	kV
Safety temperature		T_{si}			175	°C

Note

- According to DIN EN 60747-5-2 (VDE 0884) (see figure 2). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

For technical questions, contact: optocoupleranswers@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

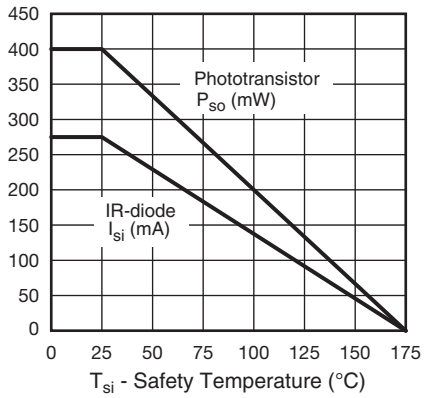


Fig. 1 - Derating Diagram

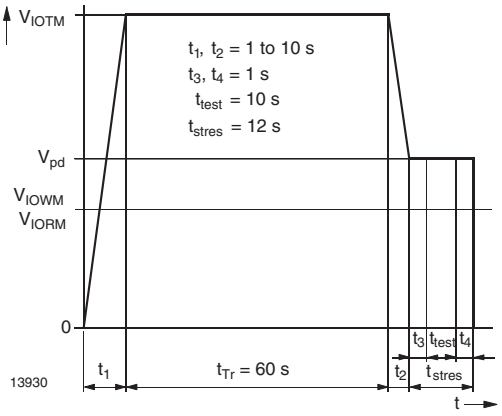


Fig. 2 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-2 (VDE 0884); IEC 60747-5-5

SWITCHING CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
NON-SATURATED						
On time	I_F = ± 10 mA, V_{CC} = 5 V, R_L = 75 Ω, 50 % of V_{PP}	t_{on}		3		µs
Rise time	I_F = ± 10 mA, V_{CC} = 5 V, R_L = 75 Ω, 50 % of V_{PP}	t_r		20		µs
Off time	I_F = ± 10 mA, V_{CC} = 5 V, R_L = 75 Ω, 50 % of V_{PP}	$t_o$ff		2.3		µs
Fall time	I_F = ± 10 mA, V_{CC} = 5 V, R_L = 75 Ω, 50 % of V_{PP}	t_f		2		µs
Propagation H to L	I_F = ± 10 mA, V_{CC} = 5 V, R_L = 75 Ω, 50 % of V_{PP}	t_{PHL}		1.1		µs
Propagation L to H	I_F = ± 10 mA, V_{CC} = 5 V, R_L = 75 Ω, 50 % of V_{PP}	t_{PLH}		2.5		µs
SATURATED						
On time	I_F = ± 10 mA, V_{CC} = 5 V, R_L = 1 kΩ, V_{TH} = 1.5 V,	t_{on}		4.3		µs
Rise time	I_F = ± 10 mA, V_{CC} = 5 V, R_L = 1 kΩ, V_{TH} = 1.5 V,	t_r		2.8		µs
Off time	I_F = ± 10 mA, V_{CC} = 5 V, R_L = 1 kΩ, V_{TH} = 1.5 V,	$t_o$ff		2.5		µs
Fall time	I_F = ± 10 mA, V_{CC} = 5 V, R_L = 1 kΩ, V_{TH} = 1.5 V,	t_f		11		µs
Propagation H to L	I_F = ± 10 mA, V_{CC} = 5 V, R_L = 1 kΩ, V_{TH} = 1.5 V,	t_{PHL}		2.6		µs
Propagation L to H	I_F = ± 10 mA, V_{CC} = 5 V, R_L = 1 kΩ, V_{TH} = 1.5 V,	t_{PLH}		7.2		µs

For technical questions, contact: optocoupleranswers@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

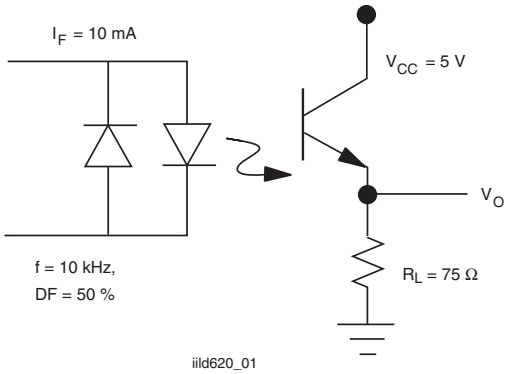


Fig. 3 - Non-Saturated Switching Timing

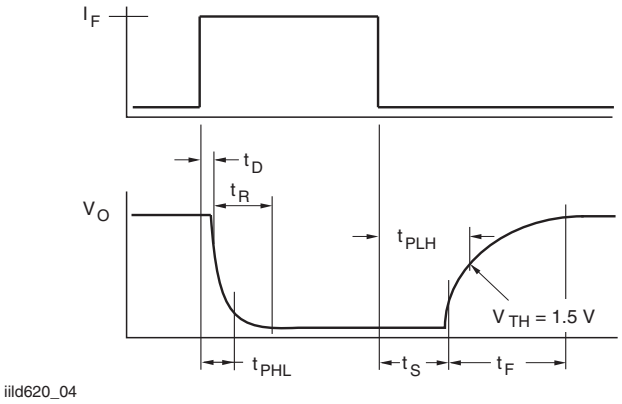


Fig. 6 - Saturated Switching Timing

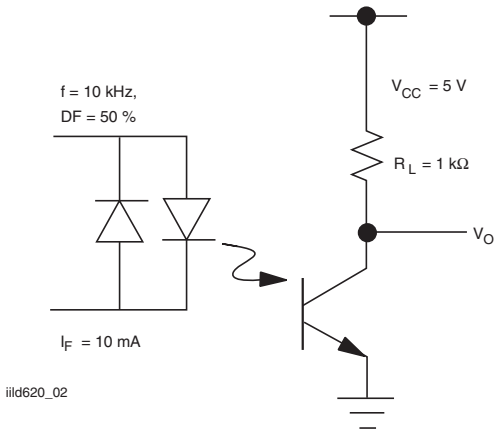


Fig. 4 - Saturated Switching Timing

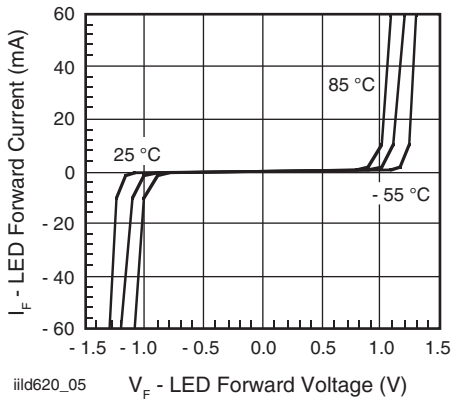


Fig. 7 - LED Forward Current vs.Forward Voltage

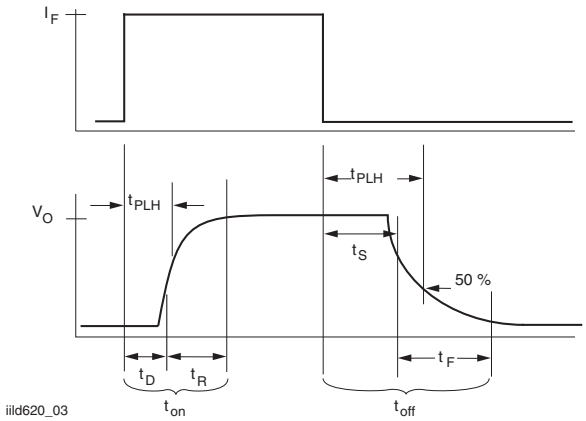


Fig. 5 - Non-Saturated Switching Timing

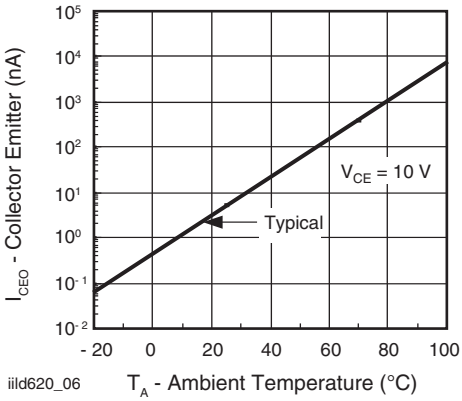


Fig. 8 - Collector Emitter Leakage vs. Temperature

For technical questions, contact: optocoupleranswers@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

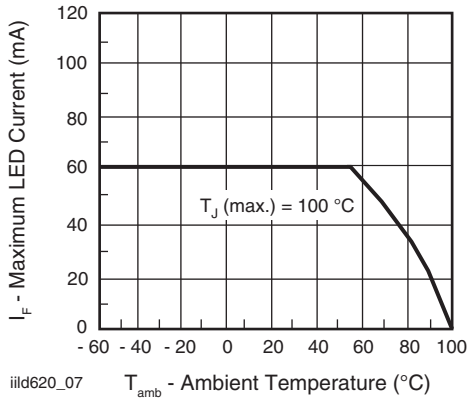


Fig. 9 - Maximum LED Current vs. Ambient Temperature

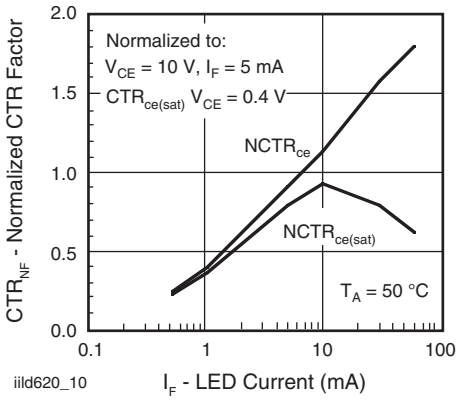


Fig. 12 - Normalization Factor for Non-Saturated and Saturated CTR vs. I_F

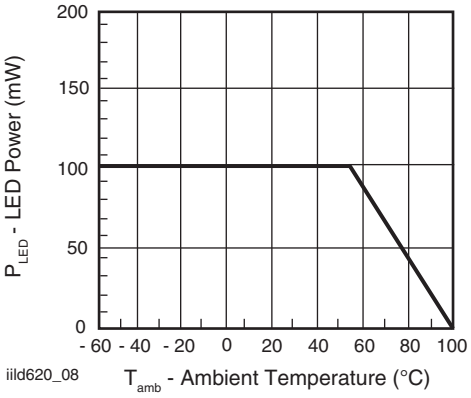


Fig. 10 - Maximum LED Power Dissipation

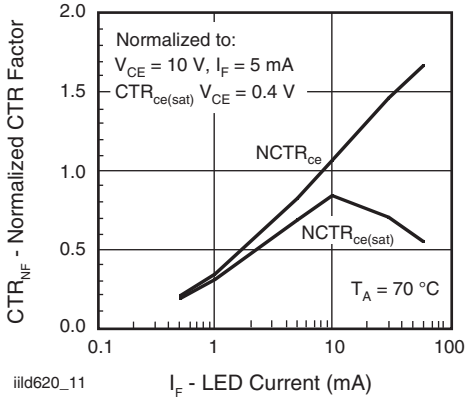


Fig. 13 - Normalization Factor for Non-Saturated and Saturated CTR vs. I_F

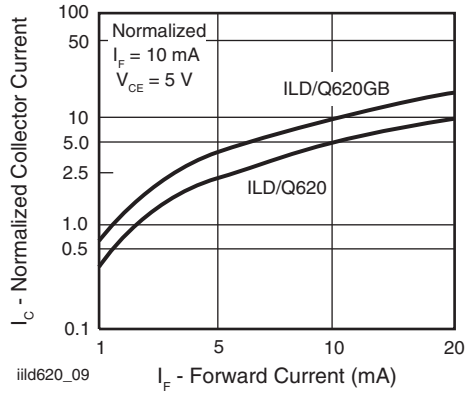


Fig. 11 - Collector Current vs. Diode Forward Current

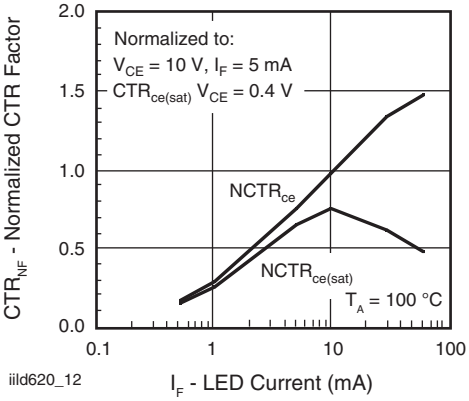


Fig. 14 - Normalization Factor for Non-Saturated and Saturated CTR vs. I_F

For technical questions, contact: optocoupleranswers@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

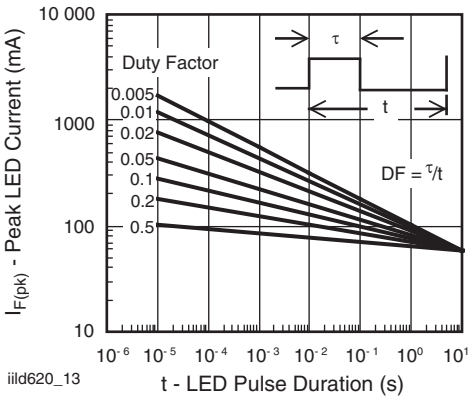


Fig. 15 - Peak LED Current vs. Pulse Duration, τ

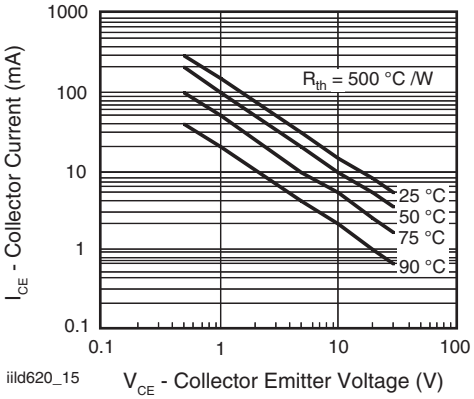


Fig. 17 - Maximum Collector Current vs. Collector Voltage

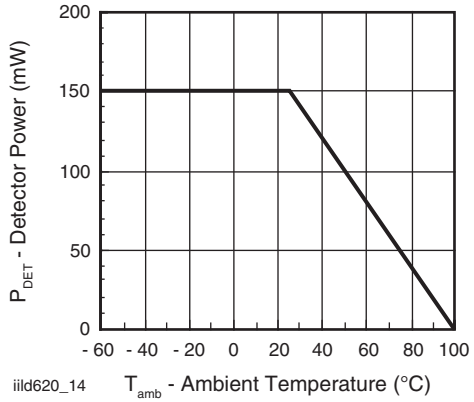
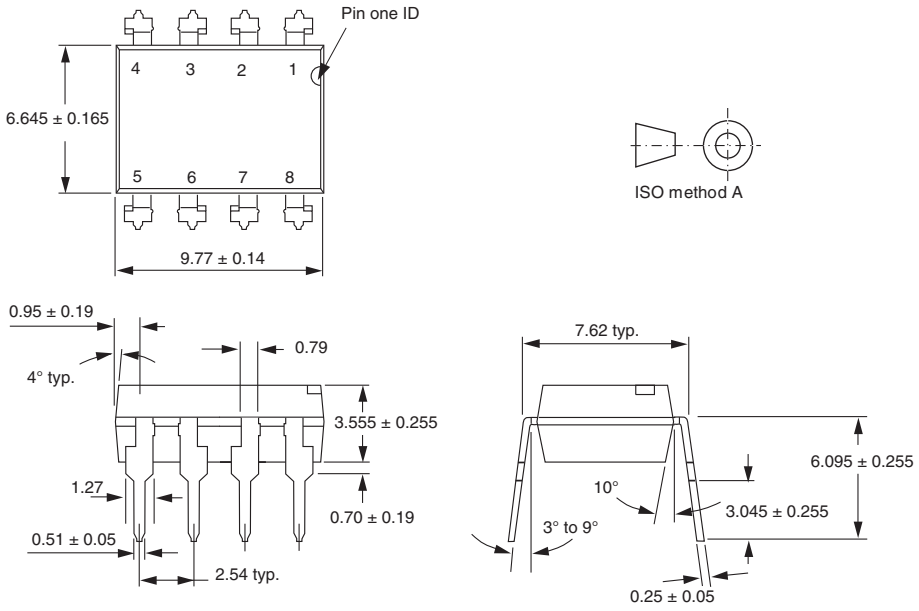
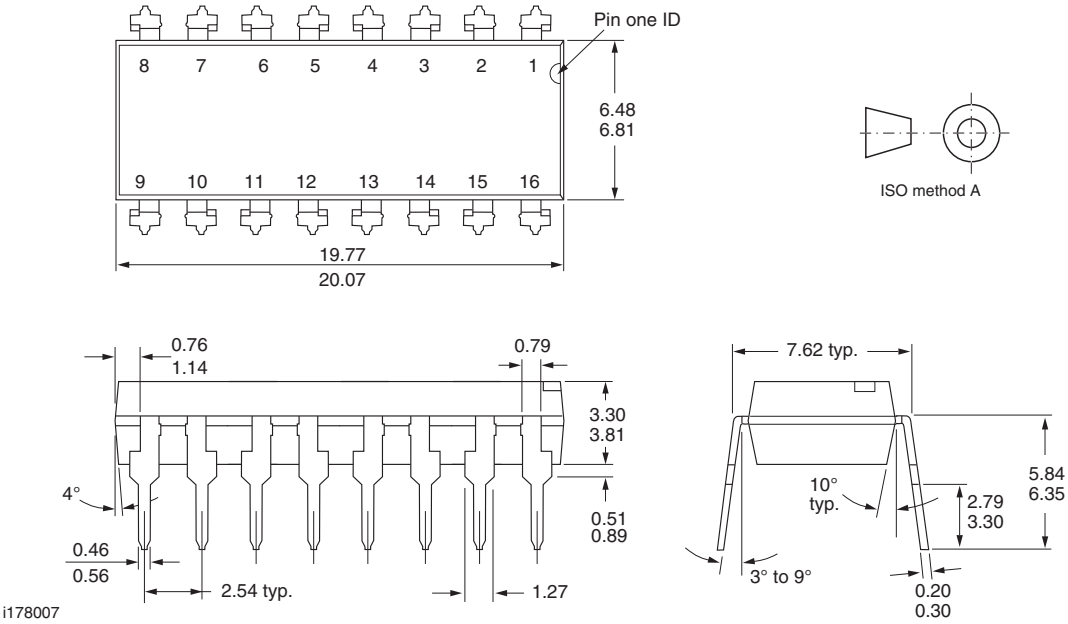


Fig. 16 - Maximum Detector Power Dissipation

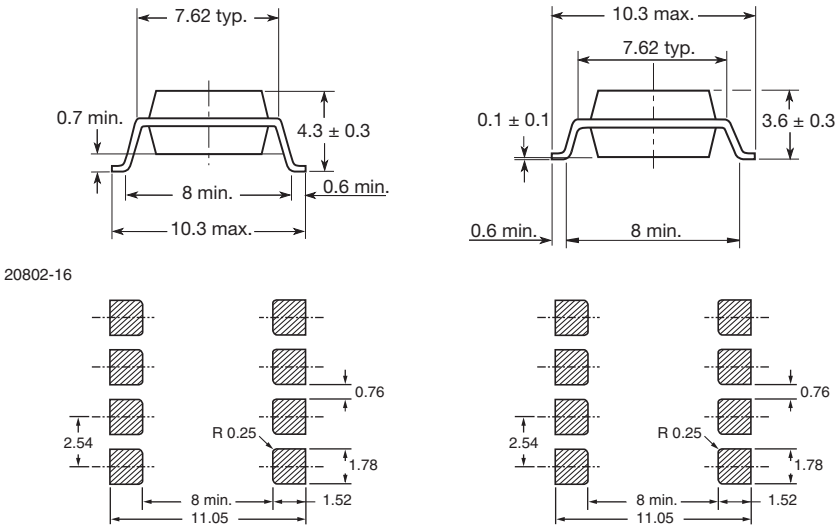
PACKAGE DIMENSIONS in millimeters



For technical questions, contact: optocoupleranswers@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



Option 7 **Option 9**



PACKAGE MARKING (example)

Notes

- Only option 1 and 7 reflected in the package marking.
- The VDE logo is only marked on option 1 parts.
- Tape and reel suffix (T) is not part of the package marking.

For technical questions, contact: optocoupleranswers@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, “Vishay”), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay’s knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer’s responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer’s technical experts. Product specifications do not expand or otherwise modify Vishay’s terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001
Адрес: 105318, г.Москва, ул.Щербаковская д.3, офис 1107

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

http://moschip.ru/get-element

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:
moschip.ru
moschip.ru_4
moschip.ru_6
moschip.ru_9